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Lead germanate ( $\text{Pb}_5\text{Ge}_3\text{O}_{11}$ ) is ferroelectric and optically active below its Curie point at  $177^\circ\text{C}^{1,2}$ . Since the signs of its optical rotatory power ( $5^\circ 35'/\text{mm}$  at  $6328\text{\AA}$ ) can be switched by the reversal of the spontaneous polarization<sup>3)</sup> without inducing any macroscopic strain, the crystal is a promising candidate as the material for electro-optic devices such as a page composer and a pattern display element. In this paper the process of the polarization reversal is analyzed and some performance characteristics as a page composer is reported.

The c-plates were cut from the poled crystal grown by the Czochralski pulling method and polished optically flat. Thin gold films were evaporated as semi-transparent electrodes and the ferroelectric domain motions could be directly observed under the polarizing microscope by applying the electric field along the c-axis<sup>4)</sup>.

With a high voltage pulse generator the electric field dependence of the nucleation rate of the antiparallel domains,  $c$ , and the sidewise velocity of the domain wall motion,  $v$ , could be separately measured, and both were found to obey the exponential laws expressed as  $c=c_\infty e^{-\alpha/E}$  and  $v=v_\infty e^{-\beta/E}$ . However, they showed different field dependence above and below  $4.5\text{KV/cm}$ . The activation fields were obtained as  $\alpha=80\text{KV/cm}$  and  $\beta=50\text{KV/cm}$  for the field above  $4.5\text{KV/cm}$  and  $\alpha=10\text{KV/cm}$  and  $\beta=13\text{KV/cm}$  for that below  $4.5\text{KV/cm}$ .

The field dependence of the total switching time  $t_s$  was also measured and the results are shown in Fig.1. As an example  $t_s$  is about  $30\mu\text{sec}$  at  $10\text{KV/cm}$ . From this figure the relevant activation field is obtained as  $61\text{KV/cm}$  above  $4.5\text{KV/cm}$  and this value agrees with the calculated one of  $60\text{KV/cm}$  using the relation<sup>5)</sup>,  $1/t_s \propto (cv^2)^{1/3}$ . For the field below  $4.5\text{KV/cm}$  the activation field was measured as  $18\text{KV/cm}$  and is a little larger than the calculated one of  $12\text{KV/cm}$ .

This crystal has not the definite threshold for the polarization reversal when driven with d.c. electric field. It was found, however, that if driven with the pulsed electric fields, there exists threshold in the pulse width, which depends on the pulse height. Because of this characteristic property  $\text{Pb}_5\text{Ge}_3\text{O}_{11}$  is particularly promising as the page composer material.

Page composers were constructed with c-plates of dimensions up to  $5 \times 5 \text{mm}^2$ . The stripes of gold films were evaporated onto the opposite faces to form matrix type electrodes. Applying electric pulses with appropriate voltage and width to the selected row and column, the part between them could be switched as a light valve due to the d-l conversion in this region. A photograph of the page composer is shown in Fig.2. This represents a part of  $16 \times 16$  bit matrix and all the valves are "on" state. The thickness of this plate is 1.3mm, the width of gold electrodes is 0.1mm, and the distance between adjacent electrodes is 0.2mm. The applied voltage is 800V with the pulse of  $50 \mu\text{sec}$ .

The contrast ratio depends on the thickness of the plates. The plate of 1mm thickness gave the contrast ratio of 40:1. The higher ratio can be achieved with thicker plates, but the electric field for domain switching becomes higher.

It was confirmed that the bit density of more than  $25/\text{mm}^2$  could be achieved for the plate of thickness of 1.9mm.

The other important properties as a page composer, such as the effect of oblique incidence of light beam will be also reported.

#### References

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Fig. 1

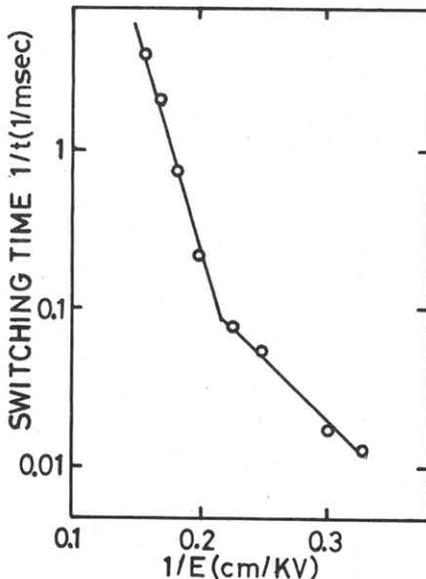


Fig. 2

